

Applications

- Cellular Handsets
- Cordless Phone
- LNBs
- CATV set top boxes

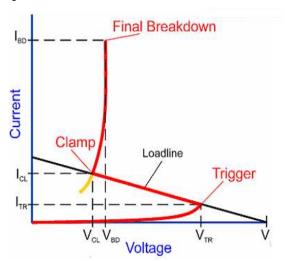
Product Features

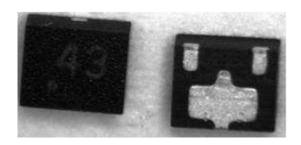
- Snap-Back ESD protection
- Low clamp voltages 15 or 30 V
- Low trigger voltages 18, 25, or 41 V
- Two bidirectional protection lines
- Fast response time, under 1 ns.
- ESD Protection: IEC 61000-4-2, level 1 JEDEC HBM, 8 kV
- Low capacitance 0.22 pF
- Thin Small Leadless SMT Package (A = 1.8 mm²)

General Description

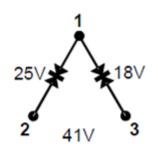
The TQP200002 ESD protection device is fabricated in GaAs MESFET technology and has been especially developed for high frequency applications. It delivers bidirectional protection with very low leakage currents and extremely low capacitance. It is ideally suited for cellular handsets, cordless phones, and broadband applications like CATV set top boxes and LNBs.

Snap-Back Characteristics:





Functional Block Diagram



Pin Configuration

	Top View	Bottom View	
Die 1 Pot	03L T/SLP (1.2×1.5mm)	3 2 1	
Pin 1 Bot _/ By Marking	6		

Symbol	Function	
VI	Measured between pin 1 and pin 3.	
V2	Measured between pin 1 and pin 2.	
V3	Measured between pin 2 and pin 3.	

Ordering Information		
Part No.	Description	
TQP200002	ESD Protector Diode	
TQP200002-PCB-75	75 Ohm Evaluation Board	
TQP200002-PCB-50	50 Ohm Evaluation Board	

Standard T/R size = 10,000 pieces on a 13" reel.